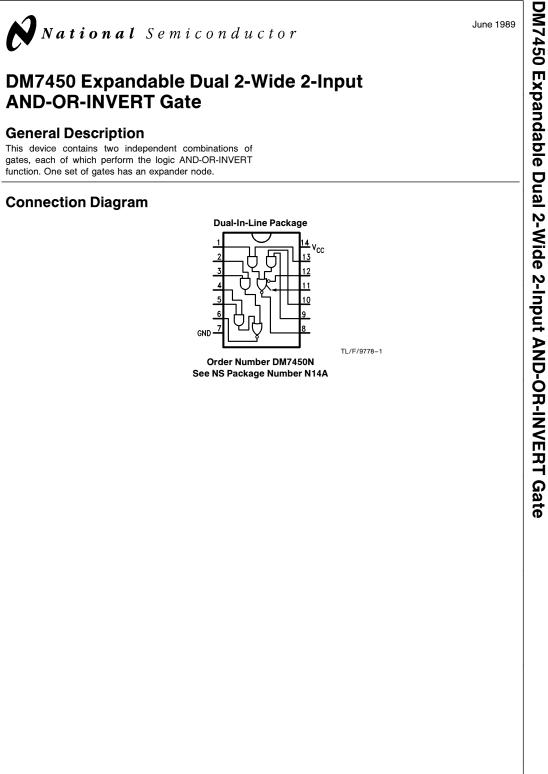


June 1989



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RRD-B30M115/Printed in U. S. A.

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply voltage	7 V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM74	$0^{\circ}C$ to $+70^{\circ}C$
Storage Temperature Range	$-65^{\circ}C$ to $+150^{\circ}C$

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

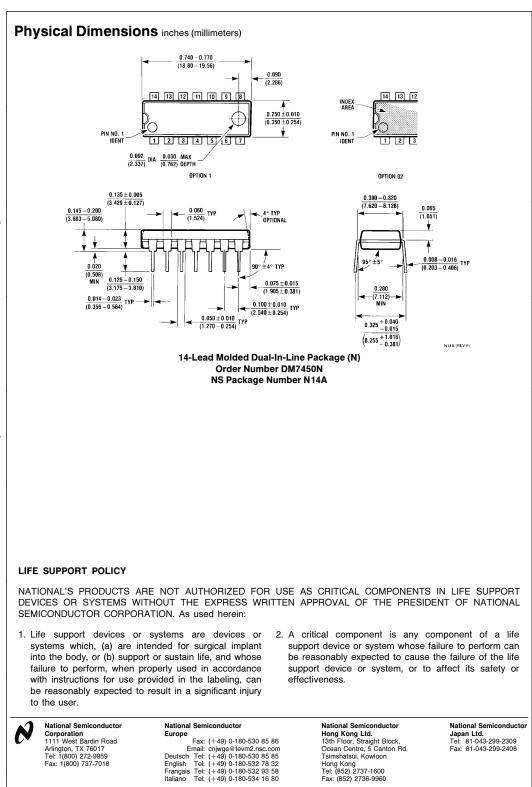
Symbol	Parameter		Units		
	i araneter	Min	Nom	Мах	Units
V _{CC}	Supply Voltage	4.75	5	5.25	V
VIH	High Level Input Voltage	2			v
VIL	Low Level Input Voltage			0.8	V
I _{OH}	High Level Output Current			-0.4	mA
I _{OL}	Low Level Output Current			16	mA
T _A	Free Air Operating Temperature	0		70	°C

Electrical Characteristics

Over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min$, $I_I = -12 \text{ mA}$			-1.5	V
V _{OH}	High Level Output Voltage	$V_{CC} = Min, I_{OH} = -400 \ \mu A$ $V_{IL} = Max$	2.4	3.4		v
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Max$		0.2	0.4	v
lı	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$			1	mA
Ι _X	Expander Current	$\begin{array}{l} V1 = 0.4V, I_{OL} = 16 \text{ mA} \\ V_{CC} = \text{Min}, T_A = \text{Min} \end{array}$			3.1	mA
I _{IH}	High Level Input Current	$V_{CC} = Max, V_I = 2.4V$			40	μΑ
IIL	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$			-1.6	mA
I _{OS}	Short Circuit Output Current	V _{CC} = Max (Note 2)	-18		-57	mA
Іссн	Supply Current with Outputs High	V _{CC} = Max			8	mA
ICCL	Supply Current with Outputs Low	V _{CC} = Max			14	mA
V _{BE(Q)}	Base-Emitter Voltage of Output Transistor Q	I1 = 0.62 mA $I_{OL} = 16 \text{ mA}$ $R_1 = 0\Omega$			1.0	v

Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time Low to High Level Output	$C_L = 15 \text{ pF}$ $R_L = 400\Omega$		22	ns
t _{PHL}	Propagation Delay Time High to Low Level Output			15	ns
	e at V_{CC} = 5V, T_{A} = 25°C. In one output should be shorted at a time.				



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Datasheets for electronics components.

National Semiconductor was acquired by Texas Instruments.

http://www.ti.com/corp/docs/investor_relations/pr_09_23_2011_national_semiconductor.html

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